

Description

The BSH205G2A uses advanced trench technology to provide excellent R $_{DS(ON)}$, low gate chargeand operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications.

General Features

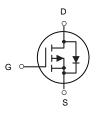
$$\begin{split} V_{DS} &= -20 V, I_D = -2.3 A \\ R_{DS(ON)} &< 140 m \, \Omega \, @ \, V_{GS} = -4.5 V \\ R_{DS(ON)} &< 170 m \, \Omega \, @ \, V_{GS} = -2.5 V \end{split}$$

Application

PWM applications Load switch







P-Channel MOSFET

Package Marking and Ordering Information

| Product ID | Pack | Brand | Qty(PCS) |
|------------|--------|------------|----------|
| BSH205G2A | SOT-23 | HXY MOSFET | 3000 |

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Limit | Unit |
|---------|--------------------------------------------------|------------|------|
| VDS | Drain-Source Voltage | -20 | V |
| Vgs | Gate-Source Voltage | ±12 | V |
| ID | Drain Current-Continuous | -2.3 | A |
| Ідм | Drain Current-Pulsed (Note 1) | -9 | A |
| PD | Maximum Power Dissipation | 0.65 | W |
| Тյ,Тѕтс | Operating Junction and Storage Temperature Range | -55 To 150 | °C |
| Reja | Thermal Resistance, Junction-to-Ambient (Note 2) | 178 | °C/W |



Electrical Characteristics (T_A=25[°]C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|-----------------------------------------------|------|------|------|------|
| Off Characteristics | · · | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =-250µA | -20 | | - | V |
| Zero Gate Voltage Drain Current | IDSS | V _{DS} =-20V,V _{GS} =0V | - | - | -1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V_{GS} =±12V, V_{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=-250\mu A$ | -0.4 | -0.7 | -1 | V |
| | | V_{GS} =-4.5V, I_D =-2A | | 130 | 140 | mΩ |
| Drain-Source On-State Resistance | Rds(on) | V _{GS} =-2.5V, I _D =-1.8A | | 152 | 170 | mΩ |
| Forward Transconductance | G FS | V _{DS} =-5V,I _D =-2A | 4 | - | - | S |
| Dynamic Characteristics (Note4) | <u> </u> | | | , | | |
| Input Capacitance | C _{lss} | | - | 285 | - | PF |
| Output Capacitance | Coss | V_{DS} =-10V, V_{GS} =0V, | - | 58 | - | PF |
| Reverse Transfer Capacitance | Crss | F=1.0MHz | - | 32 | - | PF |
| Switching Characteristics (Note 4) | i | | | | | |
| Turn-on Delay Time | t _{d(on)} | | - | 9.8 | - | nS |
| Turn-on Rise Time | tr | V_{DD} =-10V, RL=5 Ω | - | 4.9 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =-4.5V, R_{GEN} =3 Ω | - | 20.5 | - | nS |
| Turn-Off Fall Time | tf | | - | 7 | - | nS |
| Total Gate Charge | Qg | | - | 2.9 | - | nC |
| Gate-Source Charge | Q _{gs} | V_{DS} =-10V,I _D =-2A, | - | 0.45 | - | nC |
| Gate-Drain Charge | Qgd | V_{GS} =-4.5V | - | 0.75 | - | nC |
| Drain-Source Diode Characteristics | I I | | | | | L |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =-2A | - | - | -1.2 | V |
| Diode Forward Current (Note 2) | Is | | - | - | -2.0 | А |

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t ≤ 10 sec.

3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics

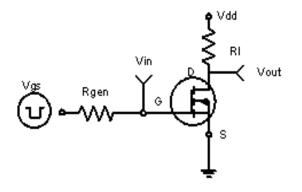


Figure 1:Switching Test Circuit

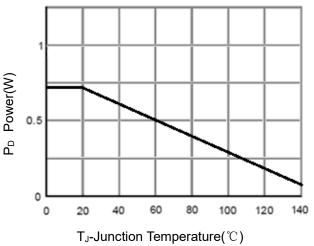
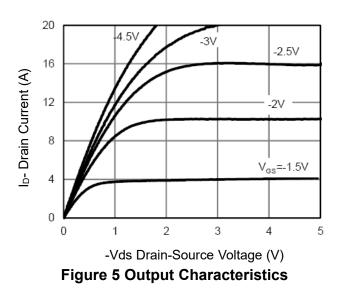


Figure 3 Power Dissipation



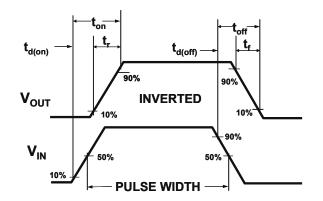


Figure 2:Switching Waveforms

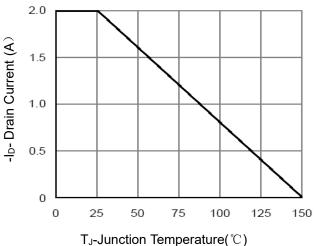
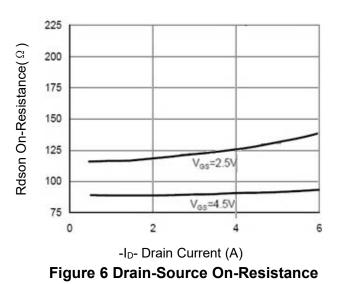
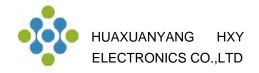
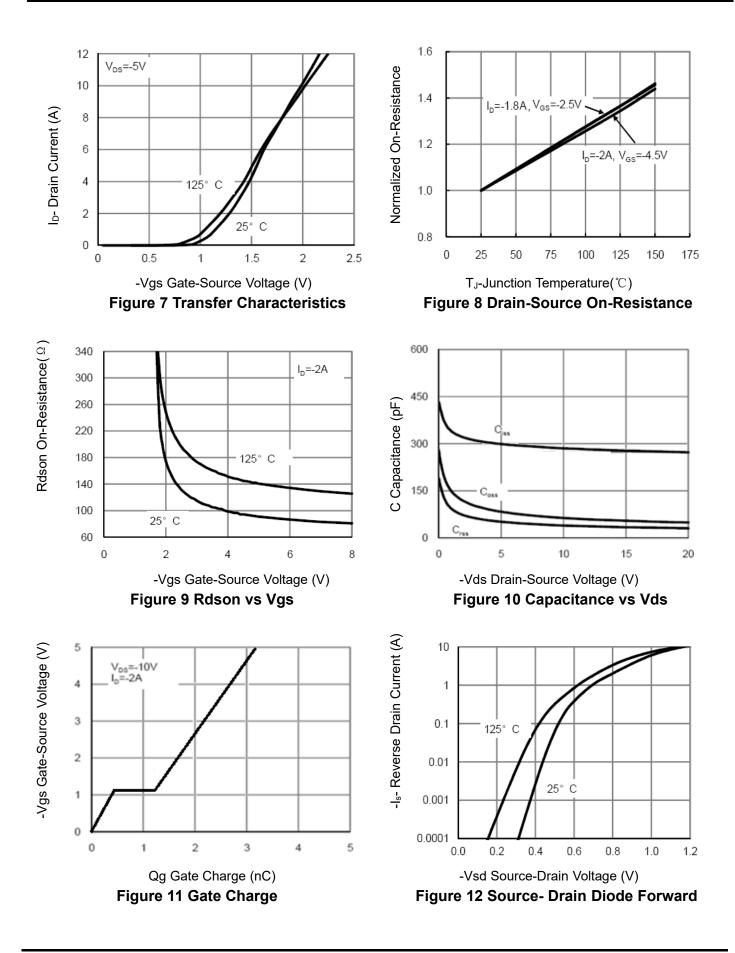


Figure 4 Drain Current









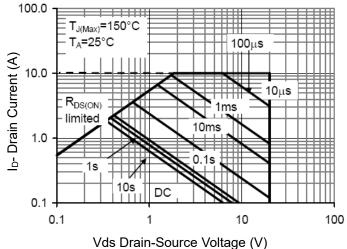


Figure 13 Safe Operation Area

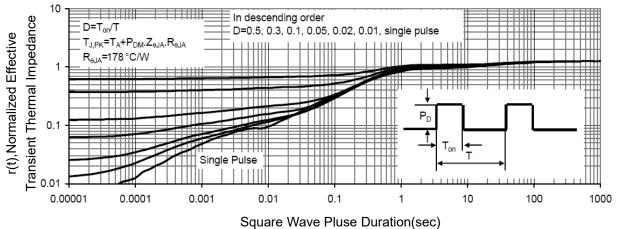
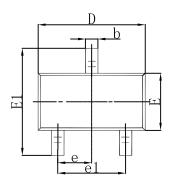
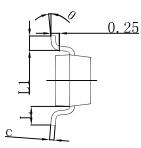


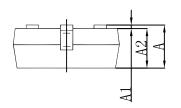
Figure 14 Normalized Maximum Transient Thermal Impedance



SOT-23 Package Outline Dimensions

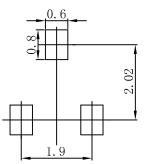






| Symbol | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|-------|----------------------|-------|--|
| | Min | Max | Min | Max | |
| Α | 0.900 | 1.150 | 0.035 | 0.045 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 | |
| b | 0.300 | 0.500 | 0.012 | 0.020 | |
| С | 0.080 | 0.150 | 0.003 | 0.006 | |
| D | 2.800 | 3.000 | 0.110 | 0.118 | |
| E | 1.200 | 1.400 | 0.047 | 0.055 | |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 | |
| е | 0.950 TYP | | 0.037 TYP | | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 | |
| L | 0.550 REF | | 0.022 REF | | |
| L1 | 0.300 | 0.500 | 0.012 | 0.020 | |
| θ | 0° | 8° | 0° | 8° | |

SOT-23 Suggested Pad Layout



Note: 1.Controlling dimension:in millimeters.

2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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